



Voltage Derating Behavior of High Temperature Capacitors for DC-Link Applications

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SABIC SPECIALTY









1976 Company established



Top 2 Chemical Brand Value*



PCIM Asia Shanghai

1950 Company established

nichicon



Leader Film capacitors **Energy Storage**



5,400 Employees around the world

200 JPY bn Net Sale



29,000 Employees

around the world



38

US\$ bn

Net Sales



63 World-class plants worldwide



Innovative products Vehicle electrification



Aggressive investments



28 **Group companies**

ULTRA THIN DIELECTRIC FILMS FOR HIGH HEAT CAPACITORS



INDUSTRY CHALLENGE

- For increased EV performance, OEMs require powertrain and capacitors to operate at higher heat and power levels
- Incumbent film capacitors, without active cooling, can operate only up to 105°C; other higher temperature films may reach 125°C. Both suffer from significant "derating" of operating voltage as temperature increases.

 Novel, thin dielectric films, capable of operating at higher temperatures at highest operating voltage.

SOLUTION:

SABIC:

- New high heat film for DC-link capacitors: ELCRES™ HTV150
- High heat materials for stable superior performing xEVs

Nichicon:

- Film capacitors that can perform at temperatures up to 150°C
- Higher power density and voltage of EV traction inverters



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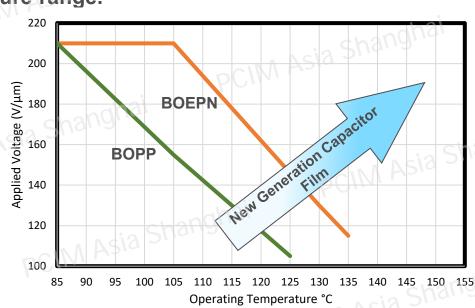
WHAT IS "DERATING" OF OPERATING VOLTAGE?



- Derating: reduction of operating voltage of polymer film capacitors at higher operating temperatures.
- For most polymers, the voltage withstanding ability decreases as temperature increases.
- Compensating for lower voltage withstanding at higher temperatures:
 - Active cooling to keep capacitor temperature low (added weight, larger volume, power consumption).
 - Rate the capacitor at lower voltage (derating).
 - Increase dielectric film thickness (overdesign) to maintain higher voltage rating.
 - Use dielectric film with stable performance over the temperature range.

Examples*:

- Series of elaborate reliability life tests at Temperature under DC Voltage for thousands of hours (e.g., 2000 hours).
- 50% V-derating, caps with BOPP film, Temp 85 → 125 °C
- 45% V-derating, caps with BOEPN film, Temp 105 → 135 °C
- Derating is also impacted by capacitor design and processing



*U. Wahner, and C. Alba, "Polymers in Film Capacitors – The Next Generation Material is available!", PCIM Europe 2023, pp. 144-149, 2023



NEW GENERATION HIGH TEMPERATURE HIGH VOLTAGE CAPACITOR FILM

ELCRES™ HTV150





E-Mobility

Traction Inverter

On-Board Charger

Electrical Compressor

DC-DC Converter

Renewable Energy

Asia Shangl

Industrial drives

Mass Transportation Inverter

Motor Drives and Controls

Inverter

ELECTRICAL CHARACTERISTICS

- Stable high D_k and low D_f up to 150°C and 100 kHz
- High breakdown strength from -40°C to 150°C
- Good self-healing
- Stable capacitance, IR, and D_f at 150°C over 2000hrs of life-testing

POTENTIAL BENEFITS

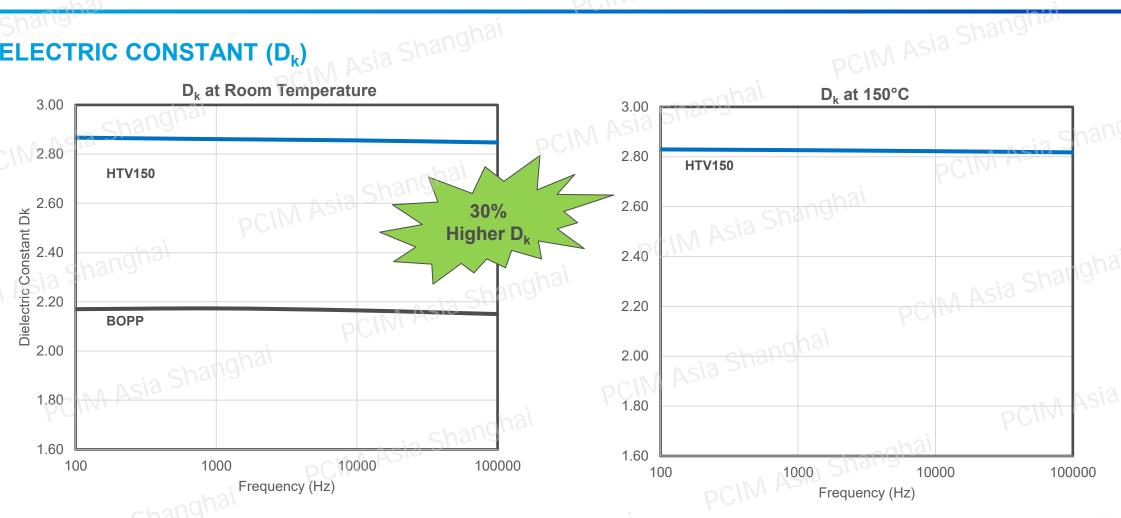
- Supports more reliable operation at elevated temperatures
- Co-location within power train improving efficiency
- Enabling the advantages of WBG chips to be fully utilized
- Downsizing or elimination of active cooling systems

ELCRES™ HTV150 film is a candidate for applications requiring high temperature resistance during processing or operation

ELCRES™ HTV150 FILM CHARACTERISTICS



DIELECTRIC CONSTANT (D_k)



DCIM Asia Shanghai

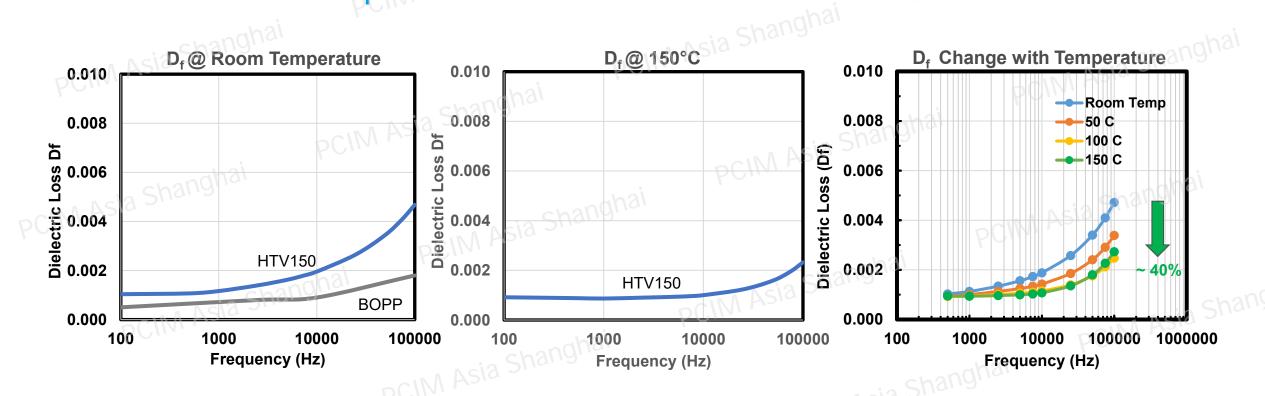
ELCRESTM HTV150 film maintains D_k performance at elevated temperatures and frequencies a Shanghai

ELCRES™ HTV150 FILM CHARACTERISTICS



PCIM Asia Shangh

FILM DIELECTRIC LOSS D_f



ıM Asia Shanghai

ELCRES™ HTV150 film offers lower dielectric losses at higher temperatures and frequencies

HIGH HEAT CAPACITOR BUILDS



- ELCRES™ HTV150 films: 5µm
- Advanced segmented metallization
- 20Ω/ 5Ω body/ heavy-edge resistivity
- 10 µF capacitors
- Flattened elements
- 6-10 capacitors per temperature condition
- Reliability life testing for 2000 hours at 105, 130, & 150 °C; under DC voltage.



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Capacitance change ΔC%

Insulation Resistance IR

Dissipation loss
 Tan δ

• Equivalent Series resistance ESR

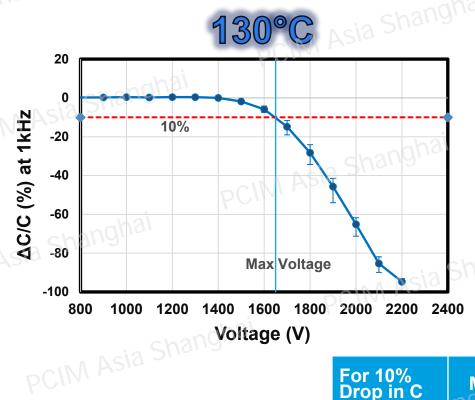


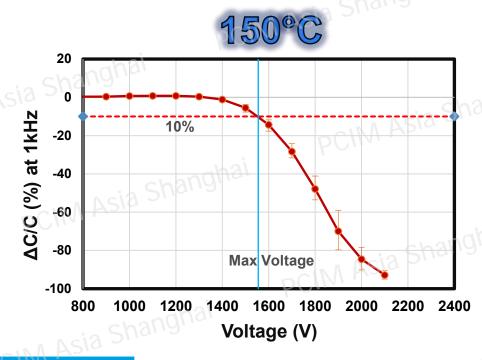
ELCRES™ HTV150 films are compatible with existing downstream metallization, slitting and capacitor building technologies

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CAPACITOR VOLTAGE STRESS TEST (5µm film), Asia Shanghai

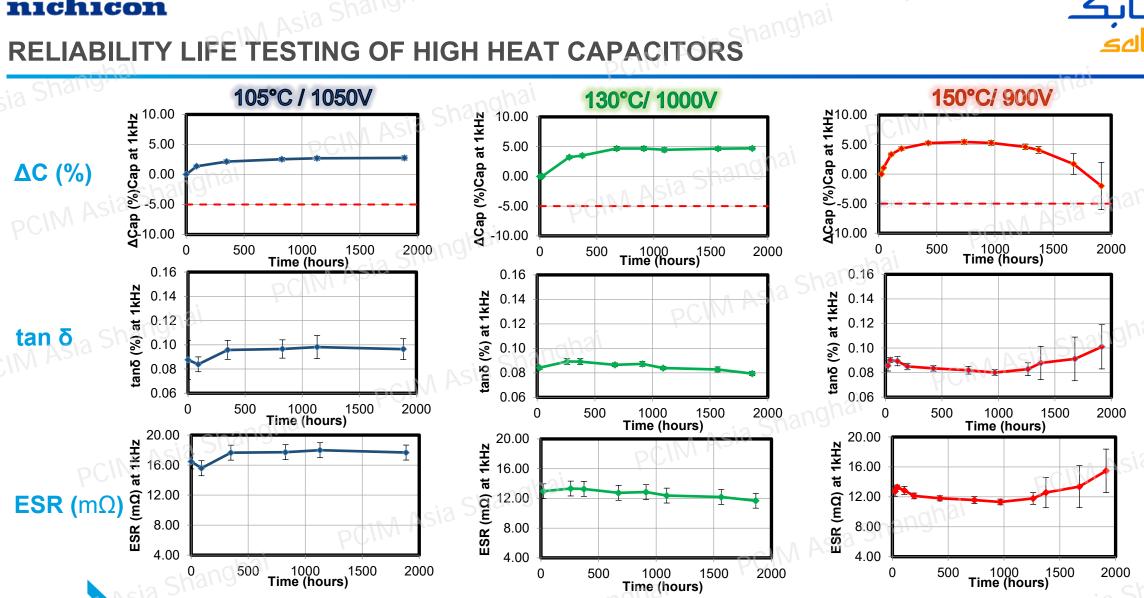




For 10% Drop in C	Max Voltage	Operating Voltage	i ol
√@130°C	1650V	1000V	shanghai
@ 150°C	1550V	900V	

@105 °C Operating Voltage of 1050V was selected for testing.

PCIM Asia Shanghai Adel Bastawros, SABIC



 $\Delta C < 5\%$, tan $\delta < 2x$ the starting value, and IR & ESR remained stable for 2000 hours

DERATING PERFORMANCE OF CAPS BUILT WITH HTV150 FILM



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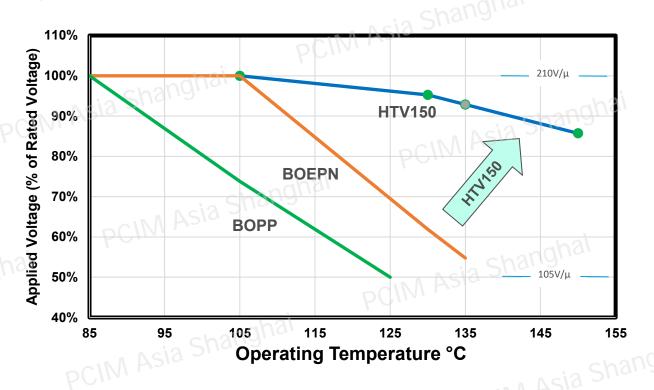
Caps with BOPP*:

Caps with BOEPN*:

o 45% Voltage Derating when Temp 105 → 135 °C

• Caps with HTV150:

- 4.8% Voltage Derating when Temp 105 → 130 °C
- 7.0% Voltage Derating when Temp 105 → 135 °C
- 14.0% Voltage Derating when Temp 105 → 150 °C



*U. Wahner, and C. Alba, "Polymers in Film Capacitors – The Next Generation Material is available!", PCIM Europe 2023, pp. 144-149, 2023

ELCRESTM HTV150 film maintains stable performance at elevated temperatures with minimal derating of capacitor operating voltage.

CONCLUDING REMARKS



■ High-heat ELCRESTM HTV150 dielectric films were used successfully to build high temperature capacitors.

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- HTV150 films were shown to retain their voltage withstanding ability at high temperatures reaching 150°C.
- Caps with HTV150 film had minimal derating of operating voltage:
 - 4.8% at 130°C
 - 7.0% at 135°C
 - 14% at 150°C
- 5µm-based capacitors were used to construct operating voltage derating curve for 105 150°C range.
- Life testing for 2000 hours were used to determine the operating voltage at 105, 130, and 150°C.
- HTV150 film offers opportunities for reducing or eliminating active cooling, downsizing, weight reduction, and lower power consumption.
- Capacitors made with HTV150 film are well positioned to help realizing full benefits of SiC and GaN MOSFETs when used in AC-DC inverters for EV applications.

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